TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74ACT157P,TC74ACT157F,TC74ACT157FN,TC74ACT157FT

#### Quad 2-Channel Multiplexer

The TC74ACT157 is an advanced high speed CMOS QUAD 2-CHANNEL MULTIPLEXER fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

This device consist of four 2-input digital multiplexer with common select and strobe inputs.

When the  $\overline{ST}$  input is held "H" level, selection of data is inhibited and all the outputs become "L" level.

The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

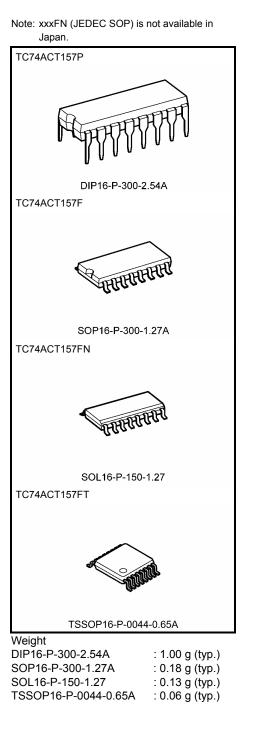
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### Features

- High speed:  $t_{pd} = 5.1 \text{ ns}$  (typ.) at VCC = 5 V
- Low power dissipation:  $I_{CC} = 8 \mu A (max)$  at  $T_a = 25^{\circ}C$
- Compatible with TTL outputs: VIL = 0.8 V (max)

 $V_{IH} = 2.0 V (min)$ 

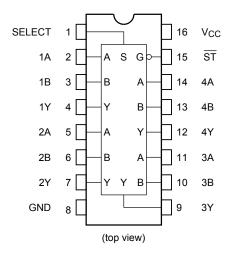
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24 \text{ mA} (\text{min})$ Capability of driving 50  $\Omega$ transmission lines.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74F157



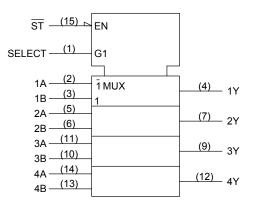
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# <u>TOSHIBA</u>

## **Pin Assignment**



## IEC Logic Symbol

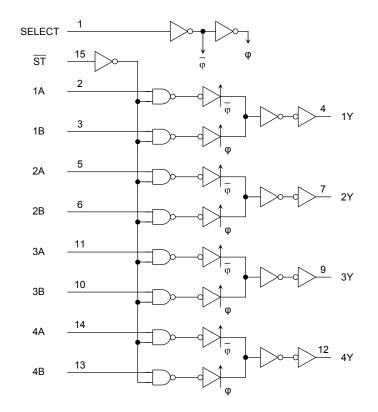


## Truth Table

	Inputs	Output		
ST	SELECT	А	В	Y
Н	Х	Х	Х	L
L	L	L	Х	L
L	L	Н	Х	Н
L	Н	Х	L	L
L	Н	Х	Н	Н

X: Don't care

#### System Diagram



#### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	I <sub>OK</sub>	±50	mA
DC output current	IOUT	±50	mA
DC V <sub>CC</sub> /ground current	ICC	±100	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C should be applied up to 300 mW.

## **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit		
Characteristics	Symbol				Min	Тур.	Max	Min	Max	Unit	
High-level input voltage	VIH	_		4.5 to 5.5	2.0	-	-	2.0	_	V	
Low-level input voltage	VIL		—		4.5 to 5.5	_	-	0.8	_	0.8	V
	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA		4.5	4.4	4.5	_	4.4	_	
High-level output voltage			I <sub>OH</sub> = −24 mA		4.5	3.94	_	_	3.80	_	V
			I <sub>OH</sub> = −75 mA	(Note)	5.5	_	_	_	3.85	_	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = 50 μA		4.5	_	0.0	0.1	_	0.1	
Low-level output voltage			I <sub>OH</sub> = 24 mA		4.5	_	_	0.36	_	0.44	V
Voltago			I <sub>OH</sub> = 75 mA	(Note)	5.5	_	—	_	_	1.65	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μA	
Quiescent supply current	ICC	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	_	_	8.0	-	80.0	μA
	Ι <sub>C</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND			5.5	_	_	1.35	_	1.5	mA

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

#### AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 $\Omega$ , input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

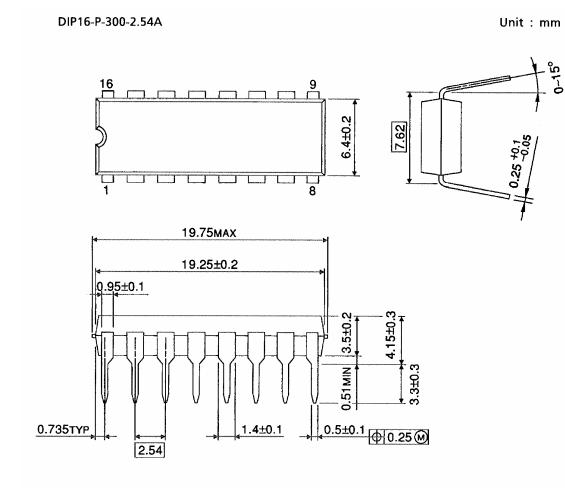
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	,		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay time (A, B-Y)	t <sub>pLH</sub> t <sub>pHL</sub>	_	5.0 ± 0.5	_	5.5	8.0	1.0	9.1	ns
Propagation delay time (SELECT-Y)	t <sub>pLH</sub> t <sub>pHL</sub>	_	5.0 ± 0.5	_	6.9	11.4	1.0	13.0	ns
Propagation delay time ( ST -Y)	t <sub>pLH</sub> t <sub>pHL</sub>	_	5.0 ± 0.5	_	6.8	10.8	1.0	12.3	ns
Input capacitance	C <sub>IN</sub>	_		_	5	10	—	10	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)	_		_	51	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$  (per bit)

## **Package Dimensions**

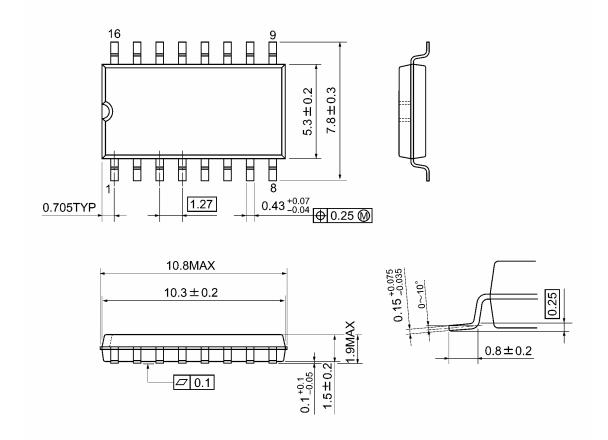


Weight: 1.00 g (typ.)

## **Package Dimensions**

SOP16-P-300-1.27A

Unit: mm

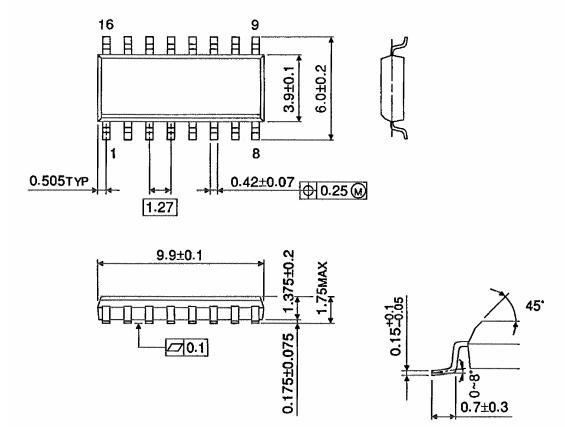


Weight: 0.18 g (typ.)

## Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



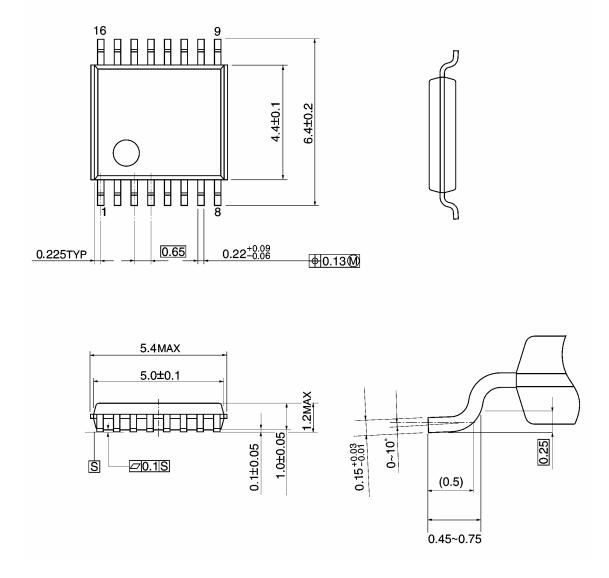
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

## **Package Dimensions**

TSSOP16-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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20070701-EN GENERAL

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